

Testing CHESS1

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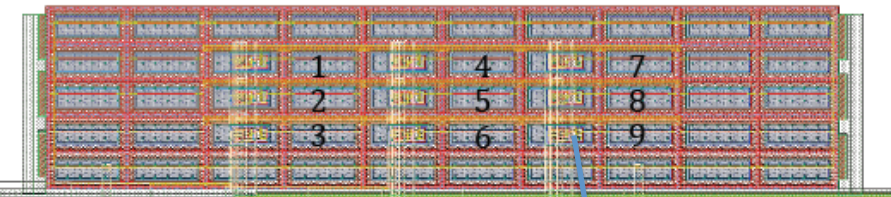
University of California, Santa Cruz

Reminder of active pixel in HV CHESS1 chip

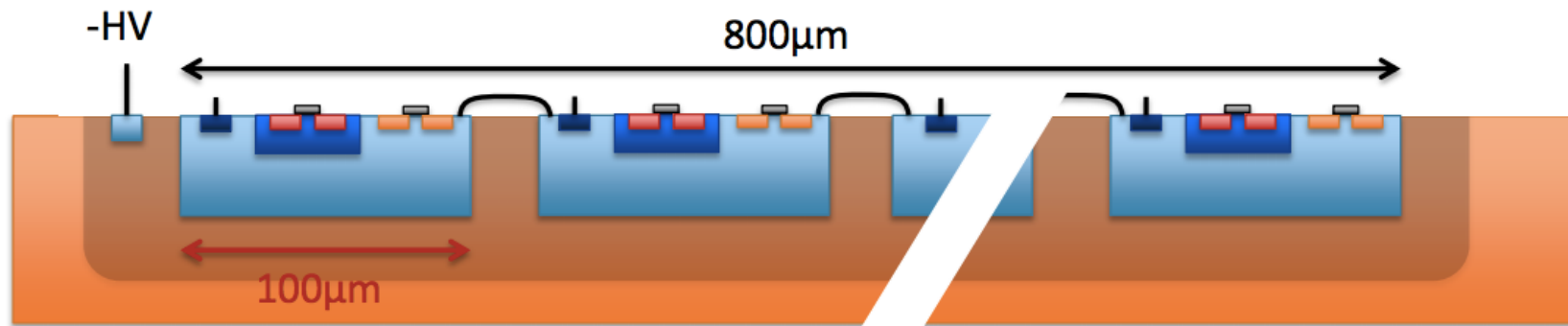
- Active pixel=passive pixel + built-in amplifier
- 4X4 pixel array
- This talk will focus on the active pixel array APA08
 - 8-Nwell inside one pixel
 - Pixel dimensions is 45X800 μm

Table 3.4-a Active Pixel Array Spatial Specification for HV-CMOS Technology

APA #	Pixel Dimensions	Diode Area Fraction
APA01	45 μm x 100 μm	30%
APA02	45 μm x 100 μm	50.4%
APA03	45 μm x 200 μm	30%
APA04	45 μm x 200 μm	50.4%
APA05	45 μm x 400 μm	30%
APA06	45 μm x 400 μm	50.4%
APA07	45 μm x 800 μm	30%
APA08	45 μm x 800 μm	50.4%

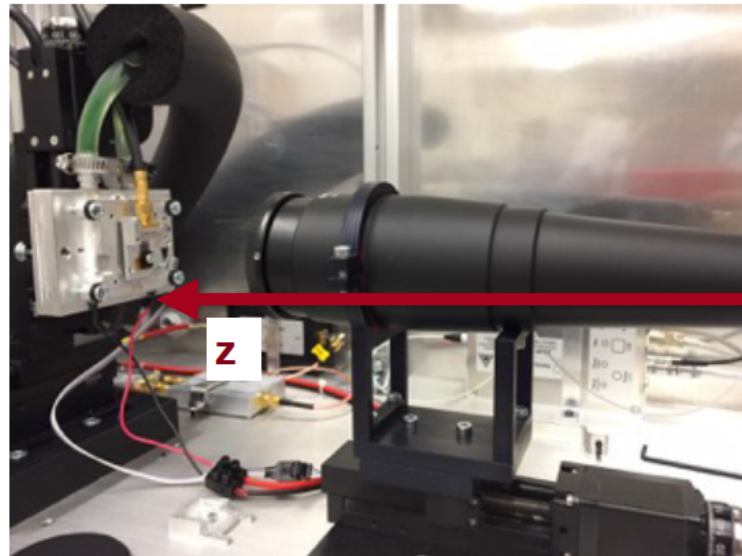
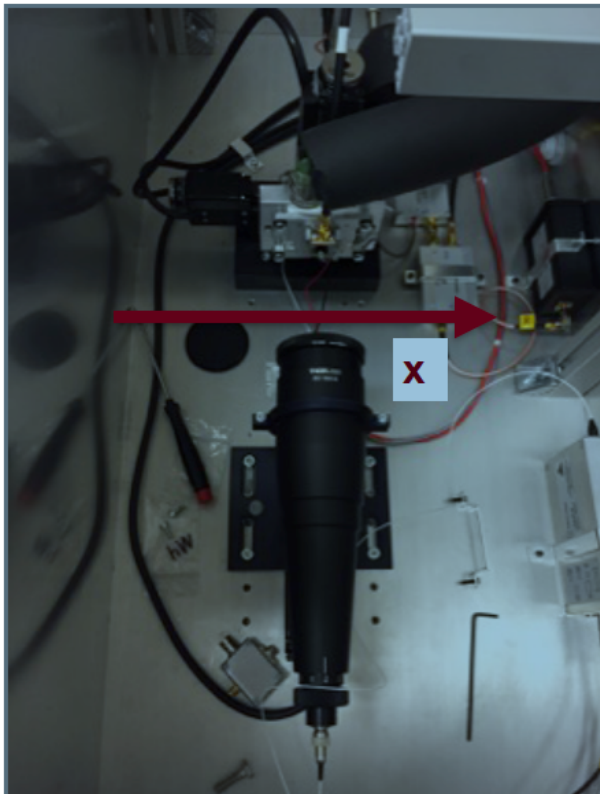


Zoom in one pixel in APA08



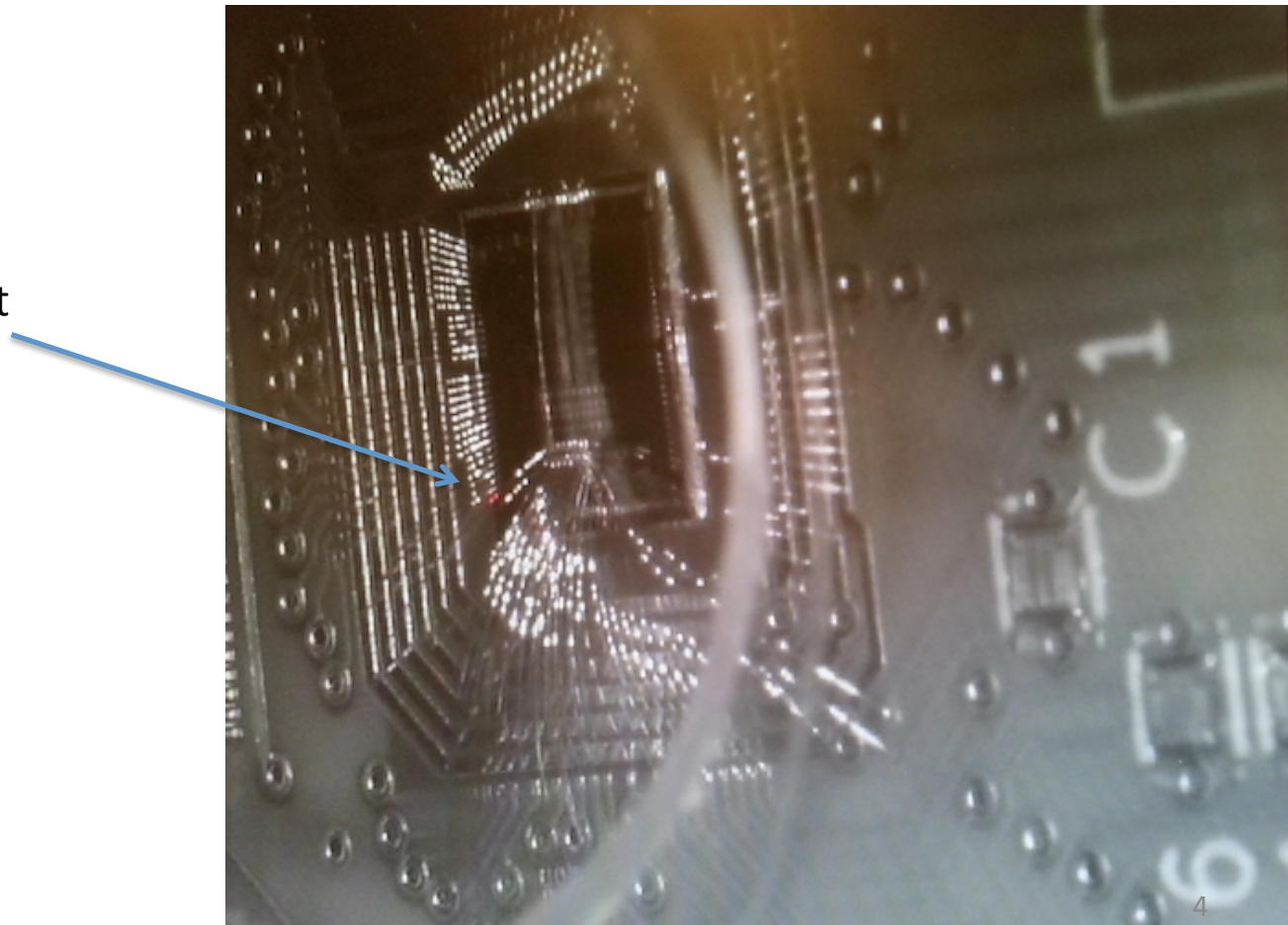
Reminder to TCT system

- Commissioning Transient Current Technique (TCT) system in UCSC
- Laser injection for CMOS chess1 active array



2D laser scan

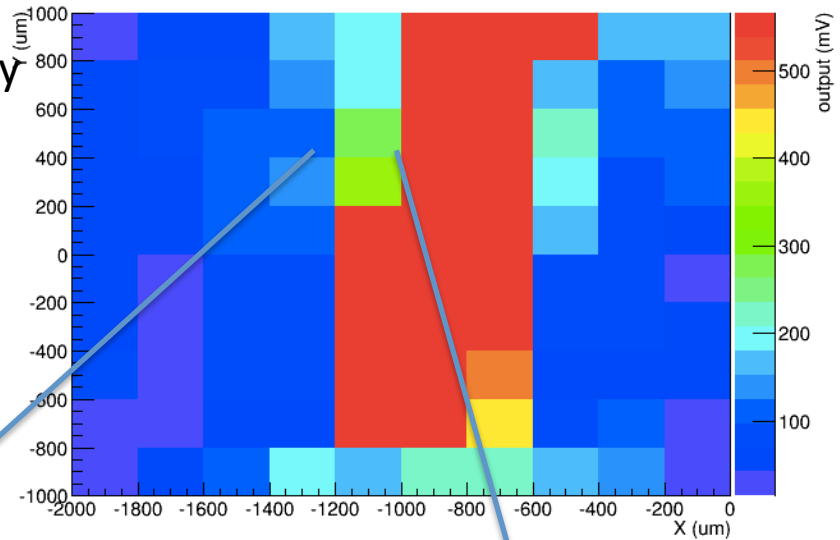
Laser beam spot



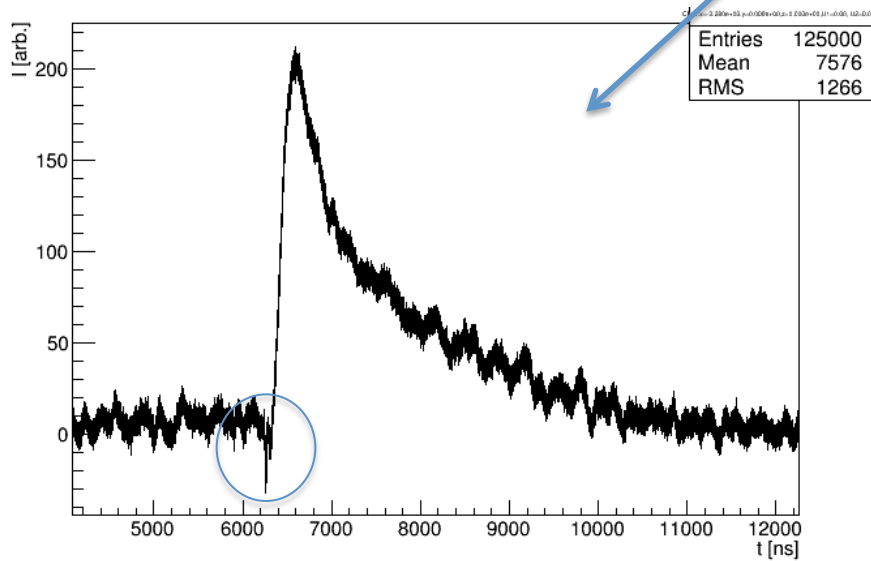
First scan

Using red laser

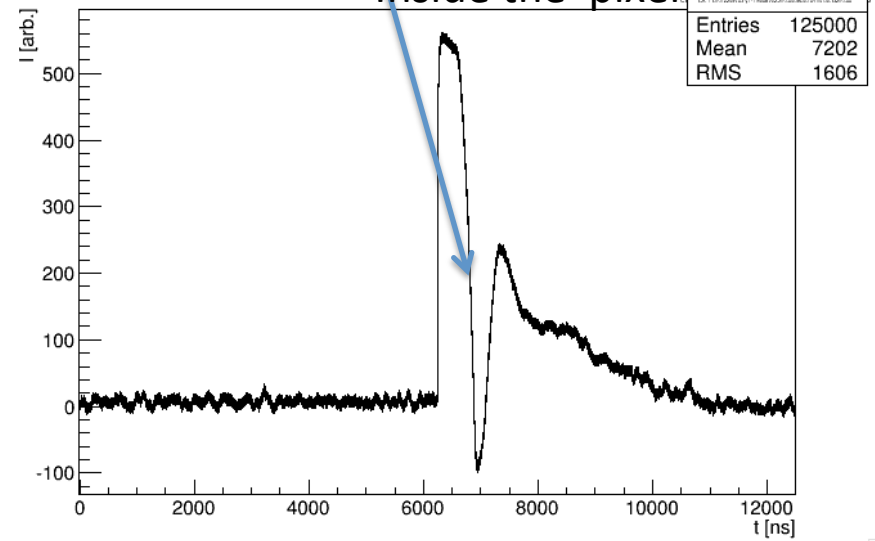
Shooting on one pixel in APA08 active array



Out of pixel region

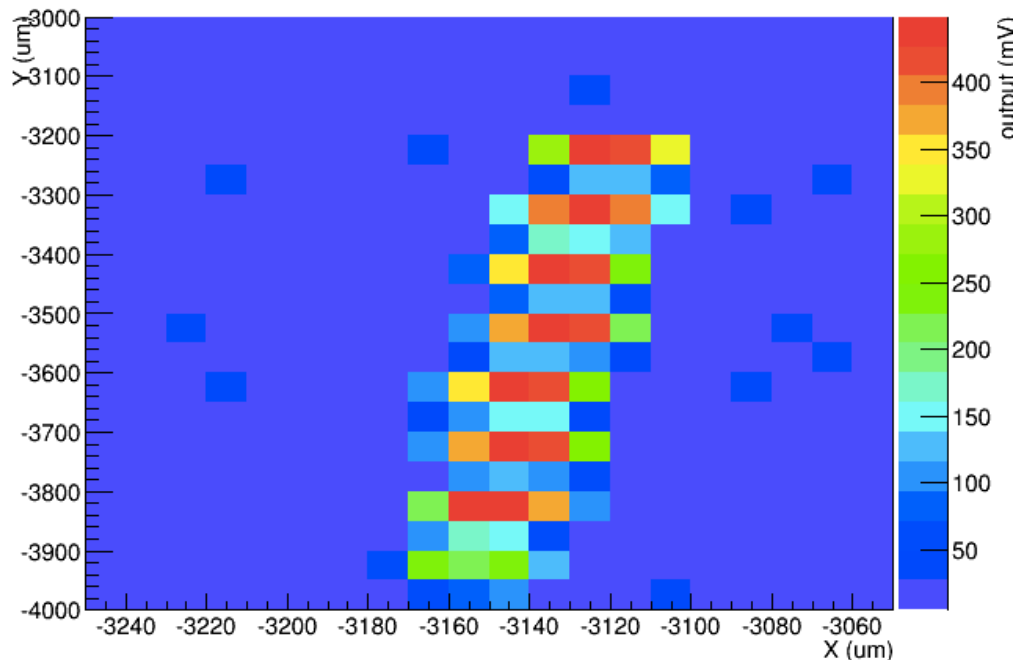


Inside the pixel



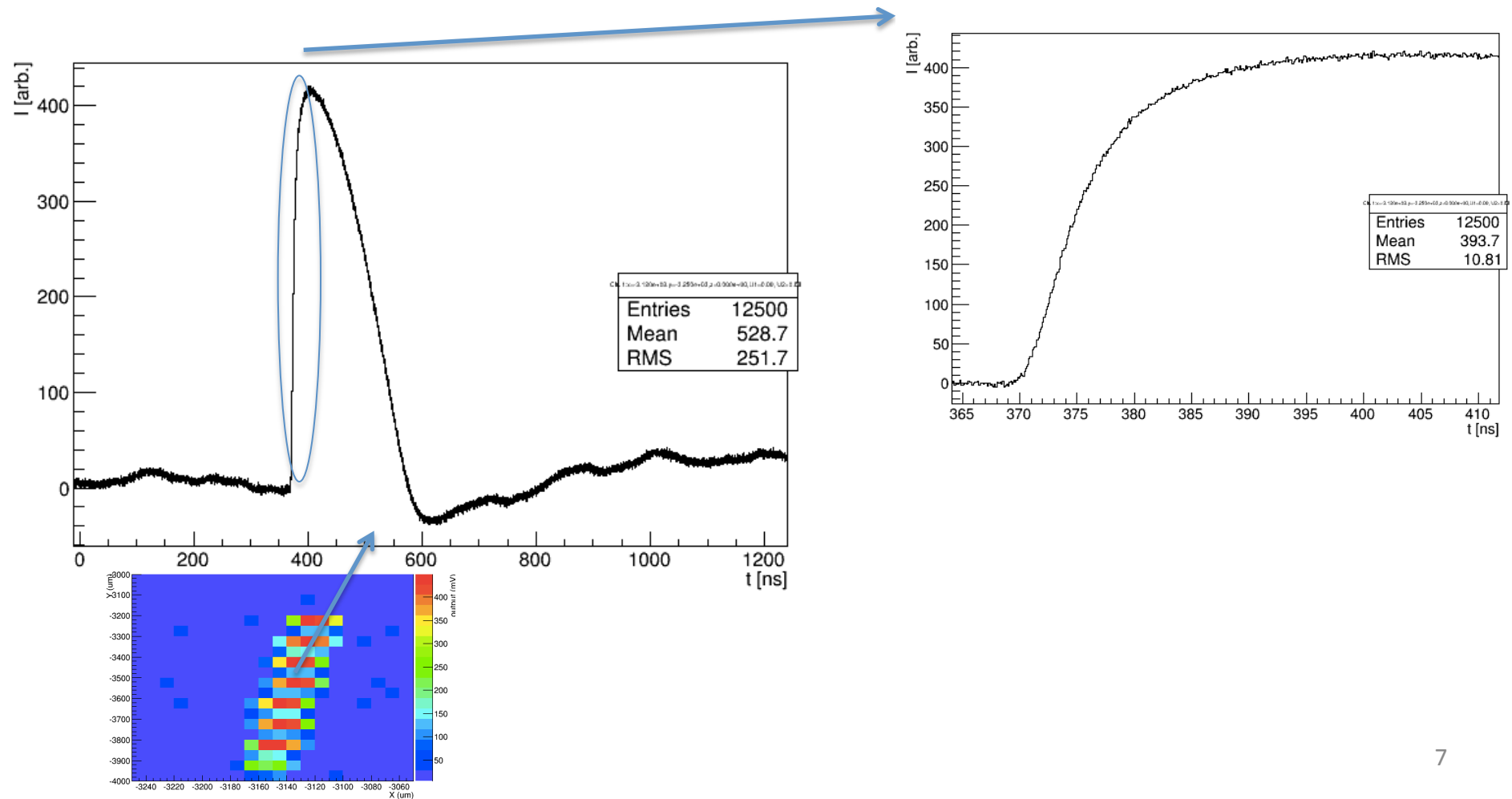
Refined laser scan on one segment of activity pixel

- Expected 8 N-well in one segment
- Red region is N-well
- Laser beam size seems is small enough to see the metal between two N-well.



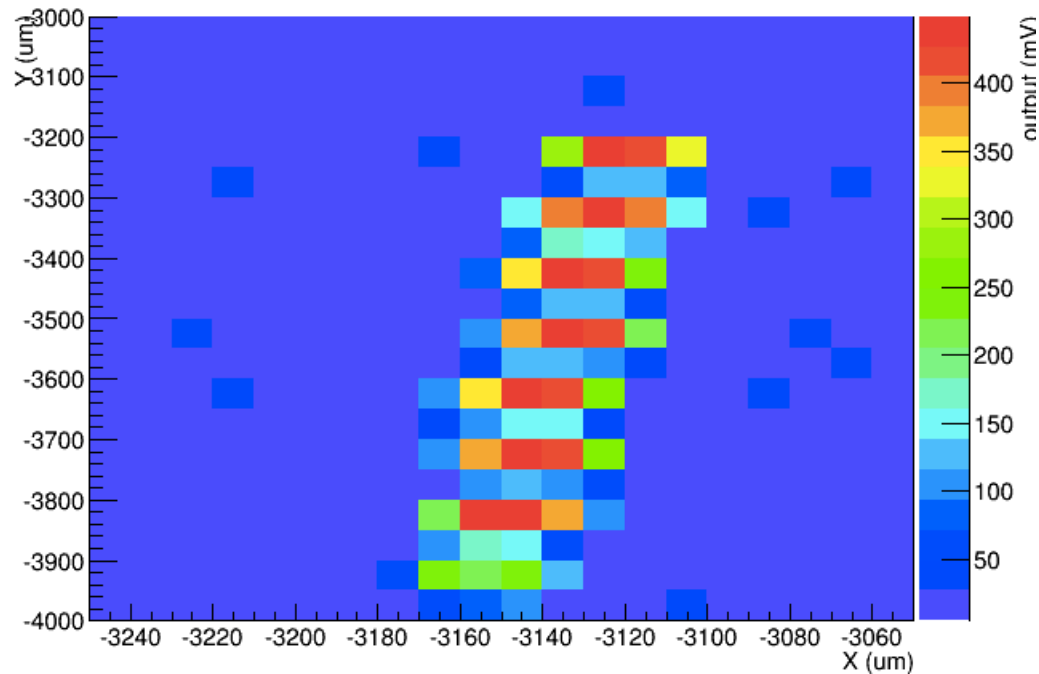
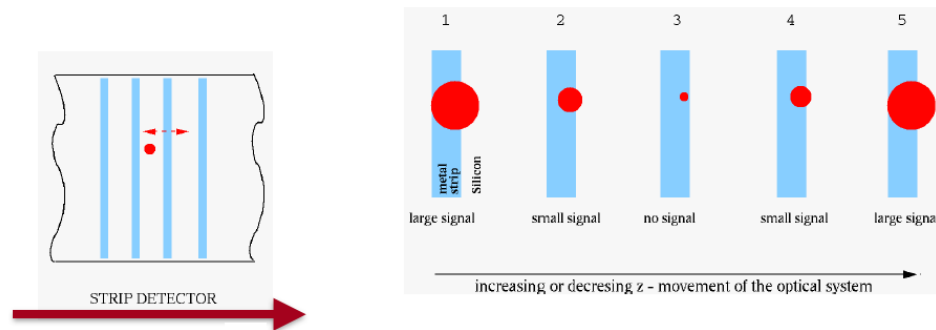
Signal pulse shape

- Very fast rise time ($\sim 15\text{ns}$)

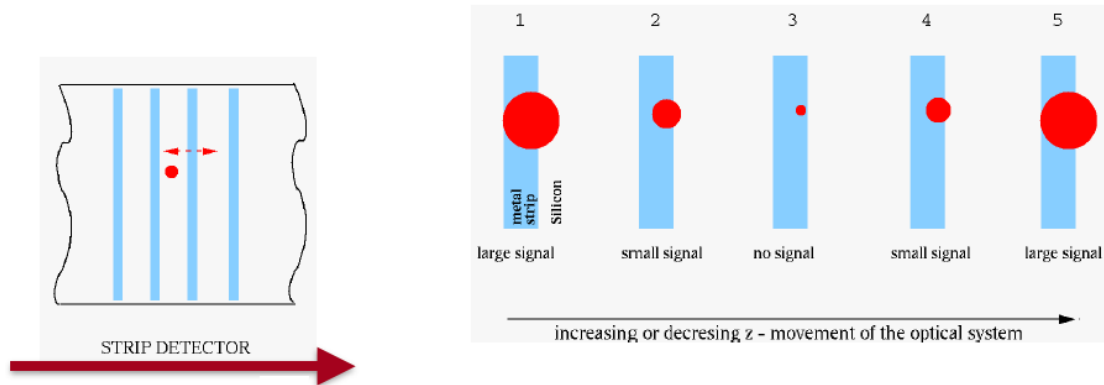


Introduction

- Use the metal between N-wells for laser focusing



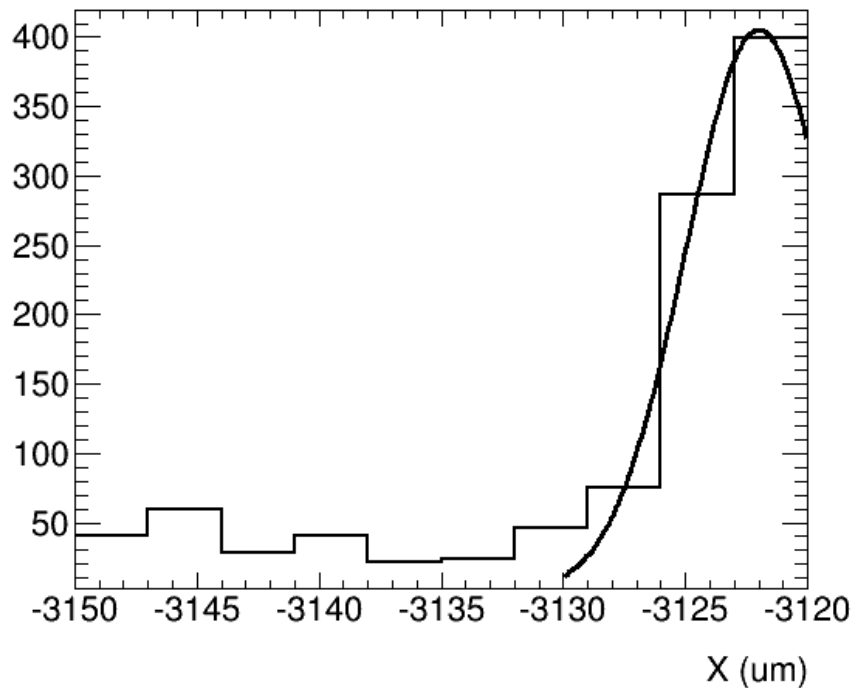
Beam spot size in different Z



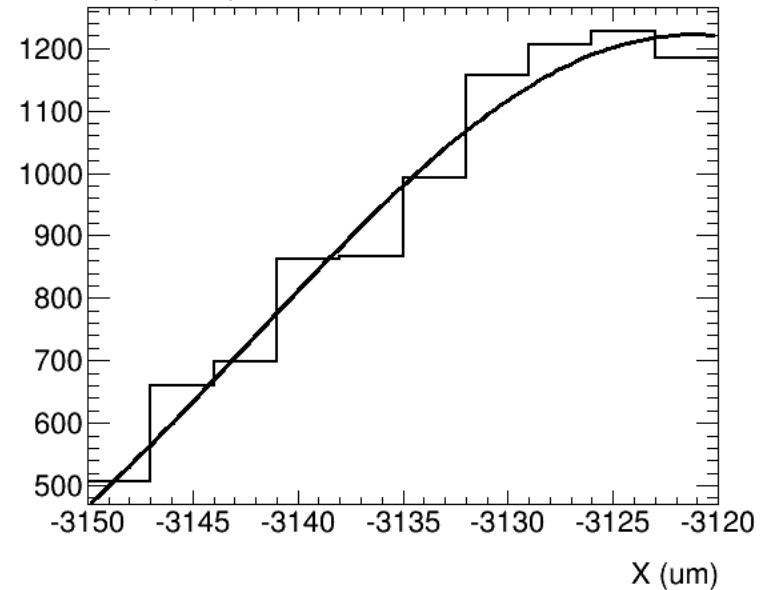
Z=-500um

Z=100um

Signal size (mV)

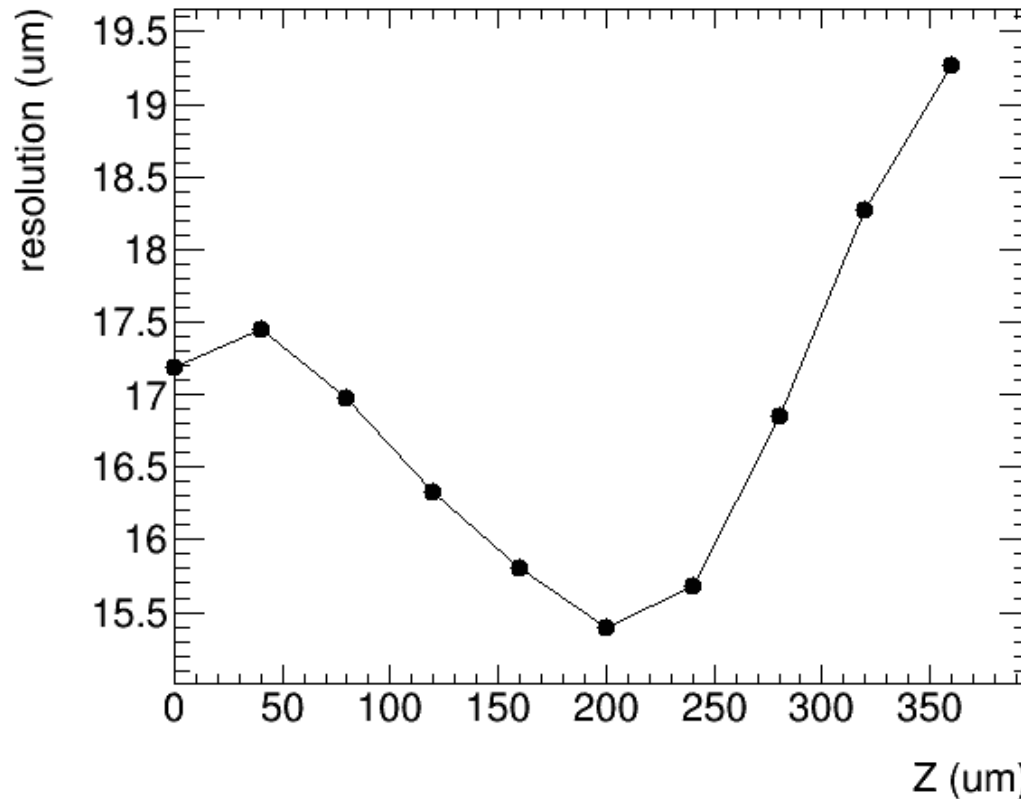
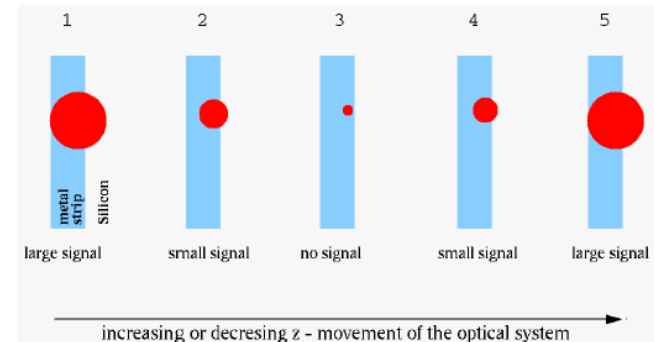
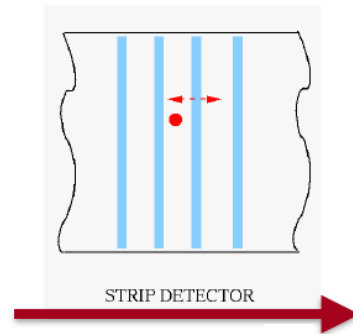


Signal size (mV)



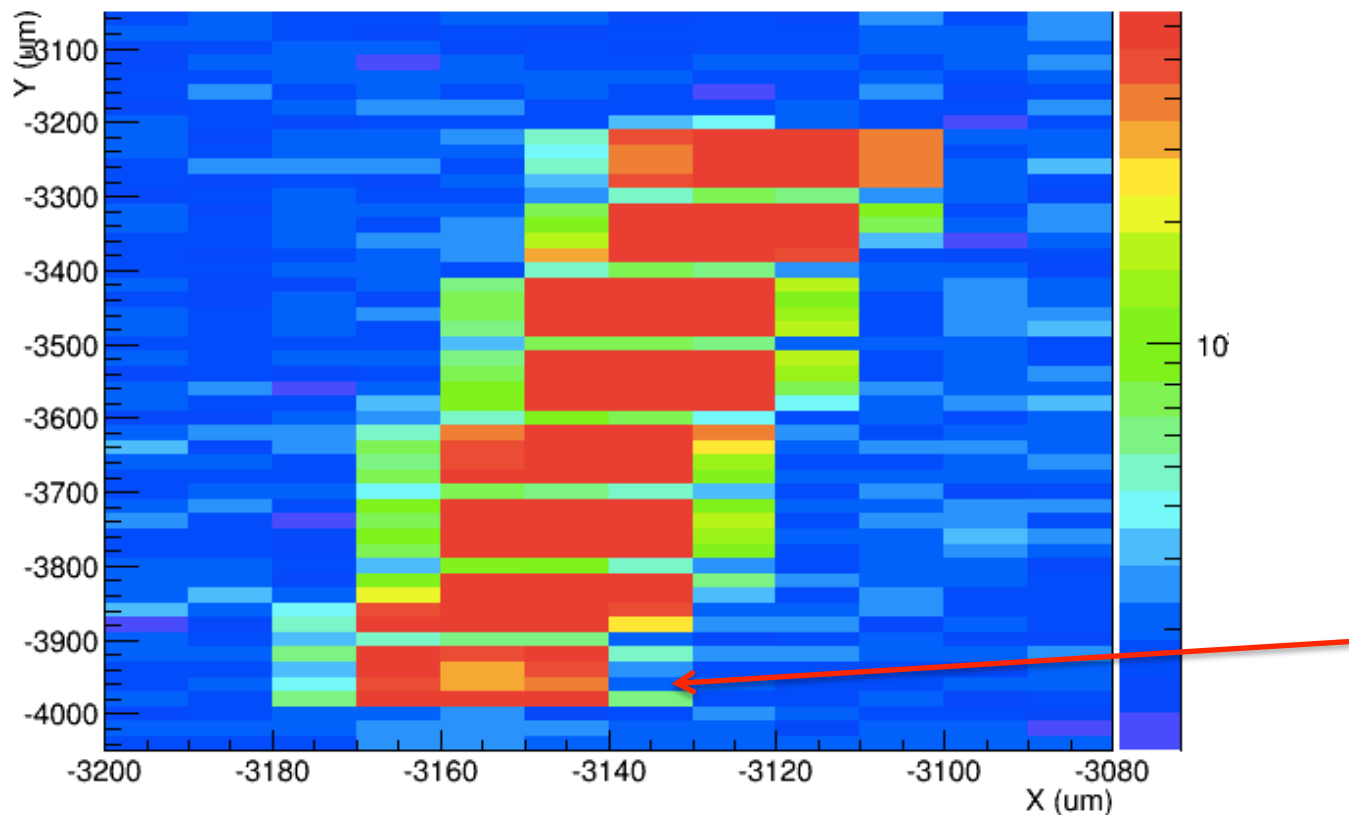
The peak is limited by X scan range

Beam spot size in different Z



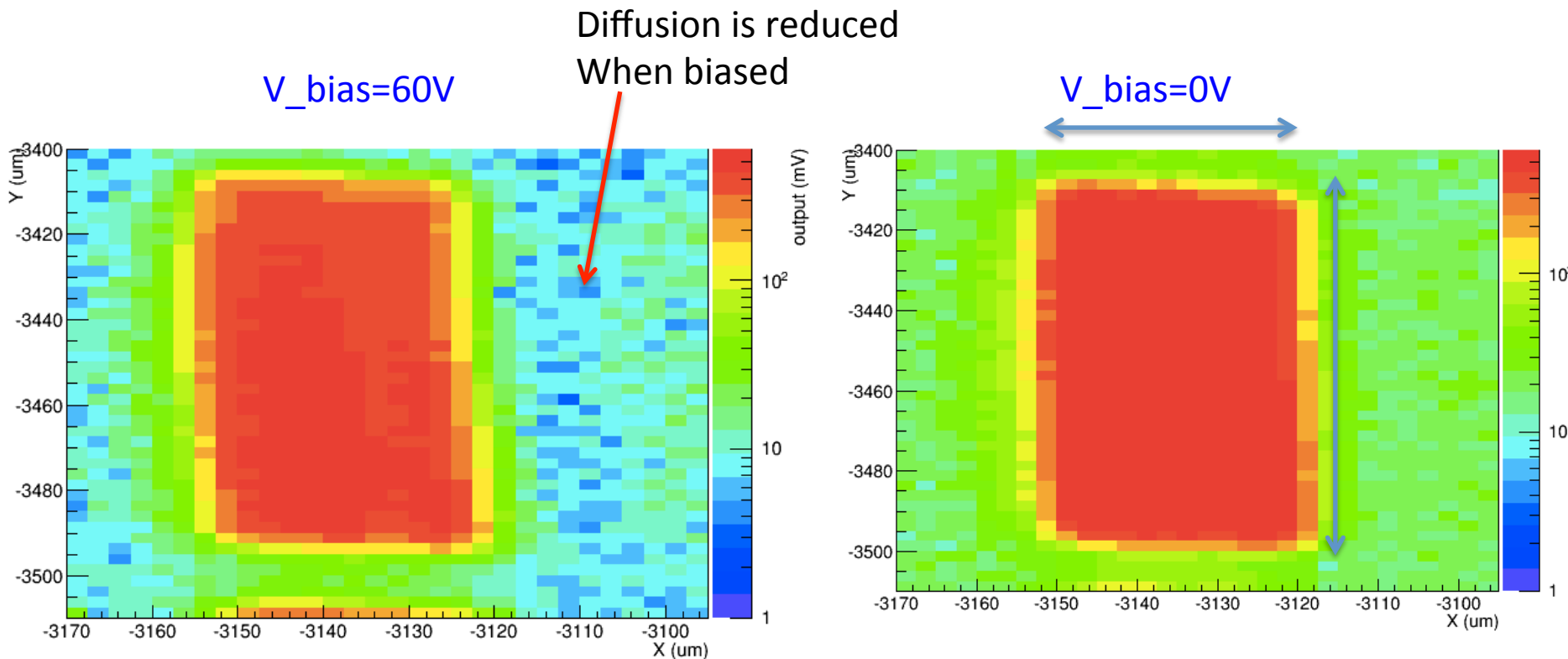
Laser scan in one pixel after focusing

- Red region is the N-well.
- Can see all 8 N-well inside one pixel
- Metal layer between each N-well.
- More metal is on the bottom N-well
 - Due to Built-in amplifier



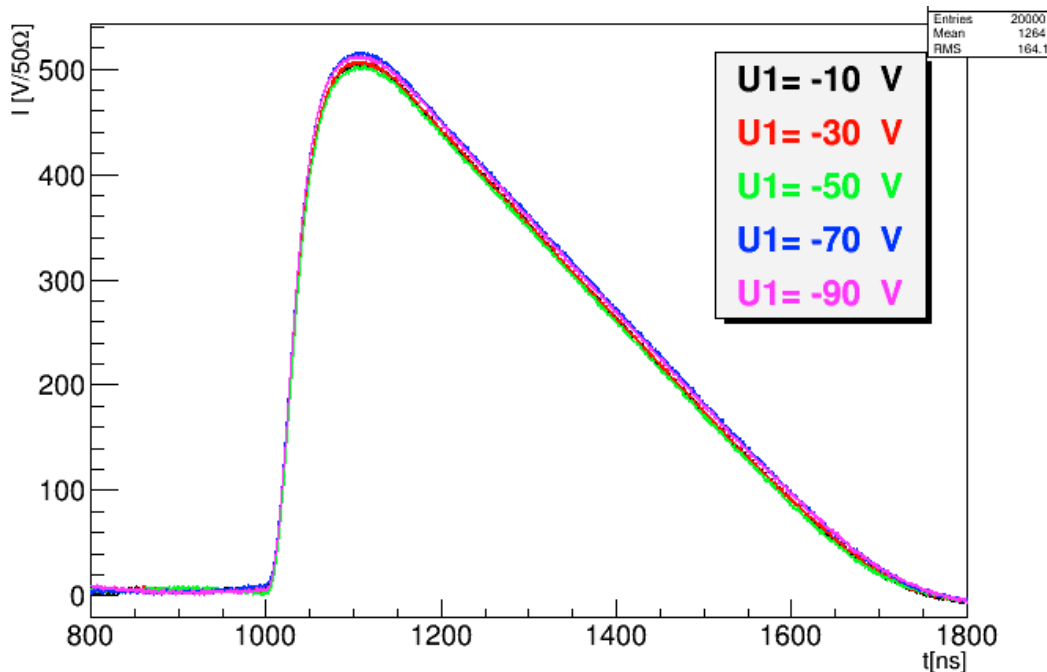
Zoom in one N-well

- Very good uniformity inside N-well



V_bias scan

- Signal response has no clear dependence of V_{bias}
- Likely to be laser power is too high
 - built-in amplifier has been saturated



Summary

- Testing one of pixel in active array
- 2D scan shows good signal response uniformity
- Next step
 - Reduce laser power to study the signal response to MIP
 - Study the bias voltage dependence